Panasonic

Zener Diode DZ2710000L

DZ2710000L Silicon epitaxial planar type

For constant voltage / For surge absorption circuit DZ2S100 in SSSMini2 type package

Features

- · Excellent rising characteristics of zener current Iz
- Low zener operating resistance Rz
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: NJ

Packaging

Embossed type (Thermo-compression sealing) 10 000 pcs / reel (standard)

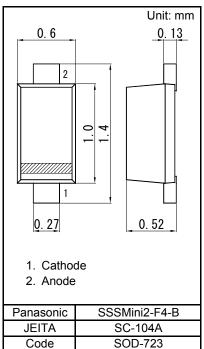
■ Absolute Maximum Ratings Ta = 25 °C

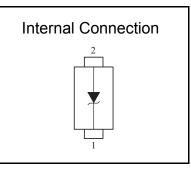
Parameter	Symbol	Rating	Unit
Repetitive peak forward current	IFRM	200	mA
Total power dissipation ^{*1}	PT	120	mW
Electrostatic discharge *2	ESD	±8	kV
Junction temperature	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C

 Storage temperature
 Tstg
 -55 to
 +150
 °(

 Note) *1: Mounted on glass epoxy print board. (45 mm x 45 mm x 1 mm) Solder in (0.4 mm x 0.3 mm)
 Solder in (0.4 mm x 0.3 mm)

*2: Test method:IEC61000_4_2(C = 150 pF,R = 330 Ω, Contact discharge:10 times)





■ Electrical Characteristics Ta = 25 °C ± 3 °C Parameter Symbol Conditions Min Max Unit Түр Forward voltage VF IF = 10 mA 1.0 V 1, *2 9.50 10.50 VZ IZ = 5 mA V Zener voltage Zener operating resistance RZ IZ = 5 mA 30 Ω Zener rise operating resistance RZK IZ = 0.5 mA 60 Ω Reverse current IR VR = 7.0 V 0.05 μA SZ mV/°C Temperature coefficient of zener voltage IZ = 5 mA 7.2

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

2. Absolute frequency of input and output is 5 MHz.

3. *1 The temperature must be controlled 25 °C for VZ mesurement.

VZ value measured at other temperature must be adjusted to VZ (25 °C)

*2 VZ guaranted 20 ms after current flow.

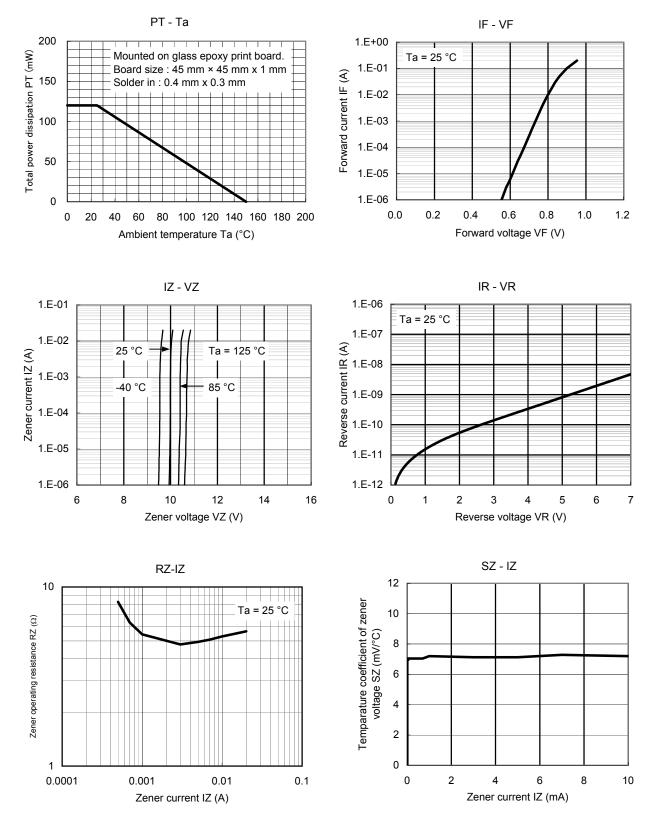
*3 Tj = 25 °C to 150 °C





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Technical Data (reference)

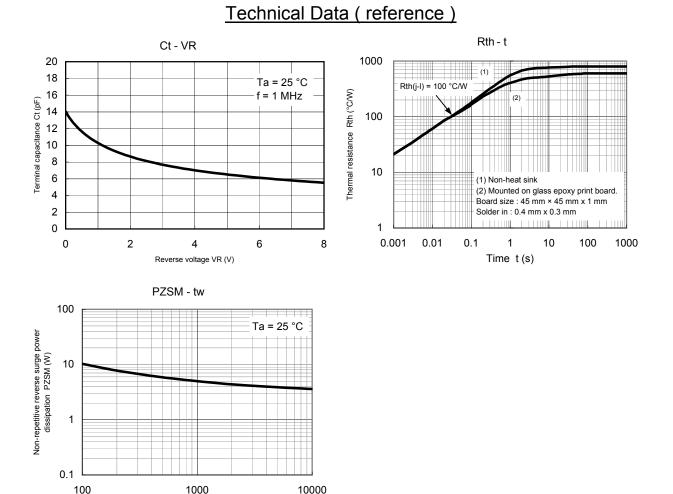


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Pulse width tw (µs)

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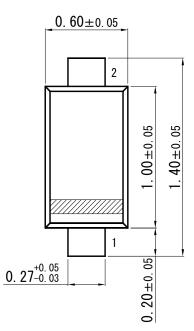
Established : 2010-02-10 Revised : 2013-10-07

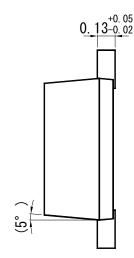


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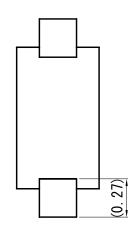
Unit: mm

SSSMini2-F4-B

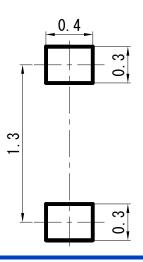




 $\begin{array}{c} 0 \text{ to } 0.05 \\ 0.52 \pm 0.03 \\ 0.52 \pm 0.03 \end{array}$



Land Pattern (Reference) (Unit: mm)



Established : 2010-02-10 Revised : 2013-10-07

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